

MOC8101
MOC8105
CNY17F-1

MOC8102
MOC8106
CNY17F-2

MOC8103
MOC8107
CNY17F-3

MOC8104
MOC8108
CNY17F-4

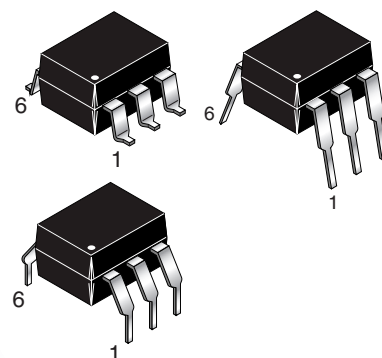
FEATURES

The MOC810X and CNY17F-X devices consist of a gallium arsenide LED optically coupled to a silicon phototransistor in a dual-in-line package.

- Closely Matched Current Transfer Ratio (CTR) Minimizes Unit-to-Unit Variation
- Narrow (CTR) Windows that Translate to a Narrow and Predictable Open Loop Gain Window
- Very Low Coupled Capacitance along with No Chip to Pin 6 Base Connection for Minimum Noise Susceptibility
- **To order devices that are tested and marked per VDE 0884 requirements, the suffix “.300” must be included at the end of part number. e.g. MOC8101.300 VDE 0884 is a test option.**

APPLICATIONS

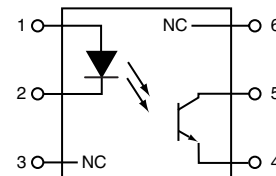
- Switchmode Power Supplies (Feedback Control)
- AC Line/Digital Logic Isolation
- Interfacing and coupling systems of different potentials and impedances



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C Unless otherwise specified)

Parameter	Symbol	Value	Unit
INPUT LED			
Forward Current - Continuous	I _F	100	mA
Forward Current - Peak (PW = 1μs, 300pps)	I _{F(pk)}	1	A
Reverse Voltage	V _R	6	Volts
LED Power Dissipation @ T _A = 25°C	P _D	140	mW
Derate above 25°C		1.33	mW/°C
OUTPUT TRANSISTOR			
Collector-Emitter Voltage	V _{CEO}	70	Volts
MOC8106/7/8, CNY17F-1/2/3/4		30	
MOC8101/2/3/4/5			
Emitter-Collector Voltage	V _{ECO}	7	Volts
Detector Power Dissipation @ T _A = 25°C	P _D	200	mW
Derate above 25°C		2.67	mW/°C
TOTAL DEVICE			
Input-Output Isolation Voltage ⁽¹⁾ (f = 60 Hz, t = 1 min.)	V _{ISO}	5300	Vac(rms)
Total Device Power Dissipation @ T _A = 25°C	P _D	260	mW
Derate above 25°C		2.94	mW/°C
Ambient Operating Temperature Range	T _{OPR}	-55 to +100	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)	T _{SOL}	260	°C

SCHEMATIC



- PIN 1. ANODE
 PIN 2. CATHODE
 PIN 3. NO CONNECTION
 PIN 4. EMITTER
 PIN 5. COLLECTOR
 PIN 6. NO CONNECTION

NOTE

1. Input-Output Isolation Voltage, V_{ISO}, is an internal device dielectric breakdown rating.

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CNY17F-1	CNY17F-2	CNY17F-3	CNY17F-4

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified) ⁽¹⁾						
Characteristic	Symbol	Min	Typ**	Max	Unit	
INPUT LED						
Forward Voltage ($I_F = 60\text{ mA}$)	V_F	1.0	1.4	1.65	V	
Reverse Leakage Current ($V_R = 5.0\text{ V}$)	I_R	—	0.001	10	μA	
Capacitance	C	—	18	—	pF	
OUTPUT TRANSISTOR						
Collector-Emitter Dark Current ($V_{CE} = 10\text{ V}$, $T_A = 25^\circ\text{C}$)	I_{CEO1}	—	1.0	50	nA	
($V_{CE} = 10\text{ V}$, $T_A = 100^\circ\text{C}$)	I_{CEO2}	—	1.0	—	μA	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	30	100	—	V	
MOC8101/2/3/4/5 ($I_C = 1.0\text{ mA}$)						
MOC8106/7/8, CNY17F-1/2/3/4 ($I_C = 1.0\text{ mA}$)		70	100	—		
Emitter-Collector Breakdown Voltage ($I_E = 100\text{ }\mu\text{A}$)	$V_{(BR)ECO}$	7.0	10	—	V	
Collector-Emitter Capacitance ($f = 1.0\text{ MHz}$, $V_{CE} = 0$)	C_{CE}	—	8	—	pF	
COUPLED						
Output Collector Current ($I_F = 10\text{ mA}$, $V_{CE} = 10\text{ V}$)	MOC8101	(CTR) ⁽²⁾	50	—	80	%
	MOC8102		73	—	117	
	MOC8103		108	—	173	
	MOC8104		160	—	256	
	MOC8105		65	—	133	
	MOC8106		50	—	150	
	MOC8107		100	—	300	
	MOC8108		250	—	600	
(I _F = 10 mA, V _{CE} = 5 V)	CNY17F-1		40	—	80	
	CNY17F-2		63	—	125	
	CNY17F-3		100	—	200	
	CNY17F-4		160	—	320	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.4	V	
CNY17F-1/2/3/4 ($I_C = 2.5\text{ mA}$, $I_F = 10\text{ mA}$)						
MOC8101/2/3/4/5/6/7/8 ($I_C = 500\text{ }\mu\text{A}$, $I_F = 5.0\text{ mA}$)						
Isolation Voltage ($f = 60\text{ Hz}$, $t = 1.0\text{ min.}$) ⁽⁴⁾	V_{ISO}	5300	—	—	Vac(rms)	
Isolation Resistance ($V_{I-O} = 500\text{ V}$) ⁽⁴⁾	R_{ISO}	10^{11}	—	—	Ω	
Isolation Capacitance ($V_{I-O} = 0$, $f = 1.0\text{ MHz}$) ⁽⁴⁾	C_{ISO}	—	0.5	—	pF	

** All typicals at $T_A = 25^\circ\text{C}$

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TRANSFER CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified)						
AC Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Unit
NON-SATURATED SWITCHING TIME						
Turn-on Time	CNY17F-1/2/3/4 Only ($R_L = 100 \Omega$, $I_C = 2 \text{ mA}$)	t_{on}	—	2	10	μs
Turn-off Time	CNY17F-1/2/3/4 Only ($V_{CC} = 10 \text{ V}$)	t_{off}	—	3	10	
Turn-On Time	All Devices ($I_C = 2.0 \text{ mA}$, $V_{CC} = 10 \text{ V}$, $R_L = 100 \Omega$) ⁽³⁾	t_{on}	—	2	—	μs
Turn-Off Time	All Devices ($I_C = 2.0 \text{ mA}$, $V_{CC} = 10 \text{ V}$, $R_L = 100 \Omega$) ⁽³⁾	t_{off}	—	3	—	
Rise Time	All Devices ($I_C = 2.0 \text{ mA}$, $V_{CC} = 10 \text{ V}$, $R_L = 100 \Omega$) ⁽³⁾	t_r	—	1	—	μs
Fall Time	All Devices ($I_C = 2.0 \text{ mA}$, $V_{CC} = 10 \text{ V}$, $R_L = 100 \Omega$) ⁽³⁾	t_f	—	2	—	
SATURATED SWITCHING TIMES						
Turn-on Time	CNY17F-1 ($I_F = 20 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)	t_{on}	—	—	5.5	μs
	CNY17F-2 ($I_F = 10 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)		—	—	8.0	
	CNY17F-3		—	—	—	
	CNY17F-4		—	—	—	
Rise Time	CNY17F-1 ($I_F = 20 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)	t_r	—	—	4.0	μs
	CNY17F-2 ($I_F = 10 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)		—	—	6.0	
	CNY17F-3		—	—	—	
	CNY17F-4		—	—	—	
Turn-off Time	CNY17F-1 ($I_F = 20 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)	t_{off}	—	—	34	μs
	CNY17F-2 ($I_F = 10 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)		—	—	39	
	CNY17F-3		—	—	—	
	CNY17F-4		—	—	—	
Fall Time	CNY17F-1 ($I_F = 20 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)	t_f	—	—	20	μs
	CNY17F-2 ($I_F = 10 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)		—	—	24	
	CNY17F-3		—	—	—	
	CNY17F-4		—	—	—	

** All typicals at $T_A = 25^\circ\text{C}$

NOTES:

1. Always design to the specified minimum/maximum electrical limits (where applicable).
2. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.
3. For test circuit setup and waveforms, refer to Figure 7.
4. For this test, Pins 1 and 2 are common, and Pins 4 and 5 are common.

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TYPICAL PERFORMANCE CURVES

Fig. 1 LED Forward Voltage vs. Forward Current

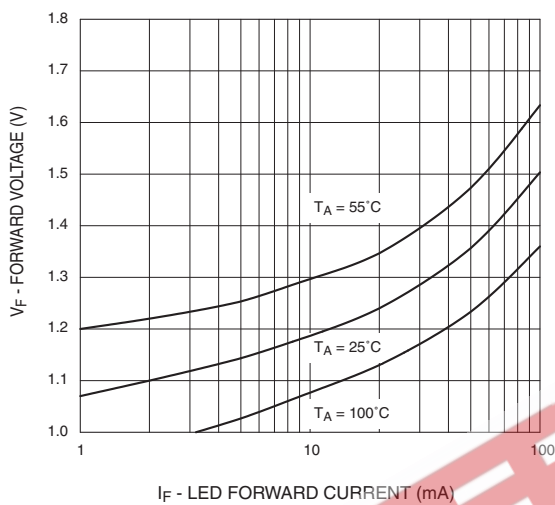


Fig. 2 Normalized CTR vs. Forward Current

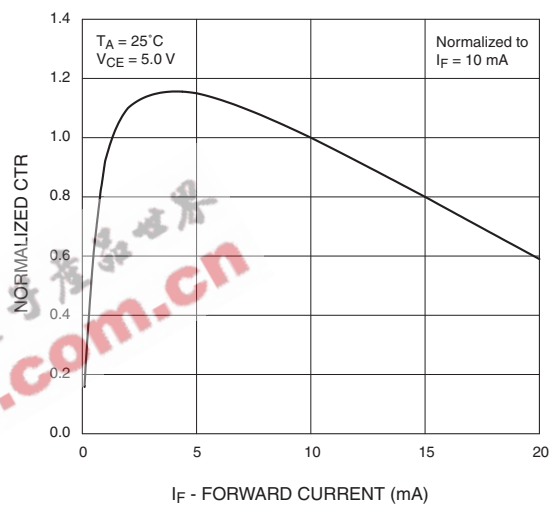


Fig. 3 Normalized CTR vs. Ambient Temperature

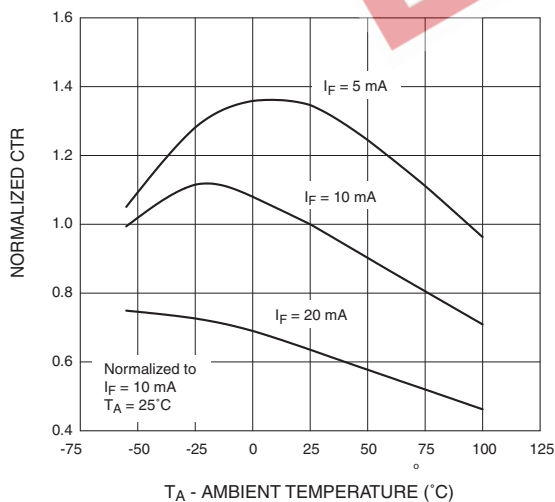
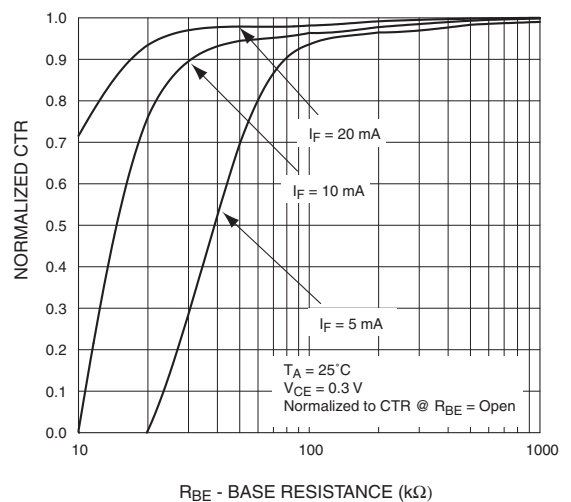


Fig. 4 CTR vs. RBE (Saturated)



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Fig. 5 CTR vs. R_{BE} (Unsaturated)

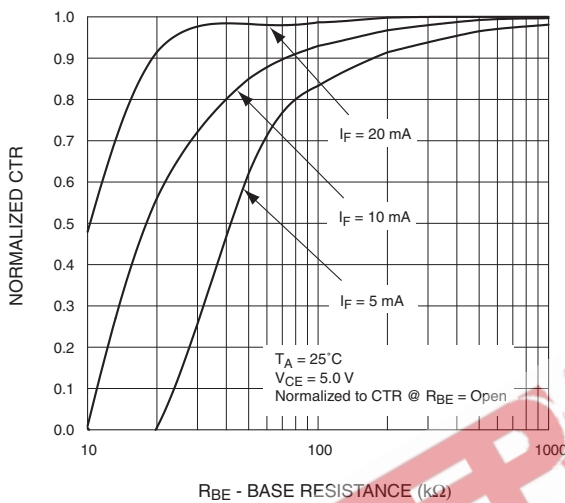


Fig. 6 Collector Emitter Saturation Voltage vs Collector Current

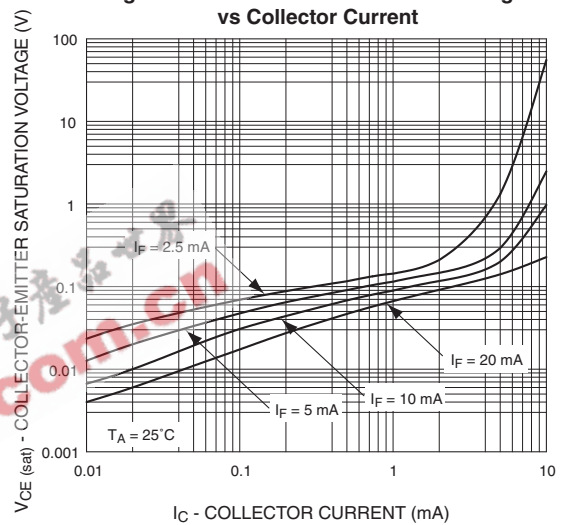


Fig. 7 Normalized t_{on} vs. R_{BE}

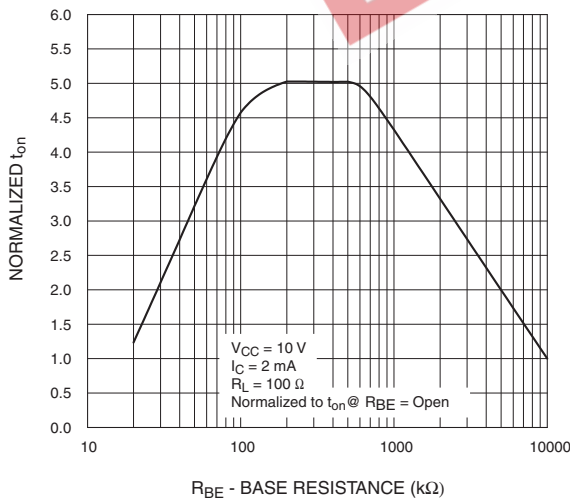
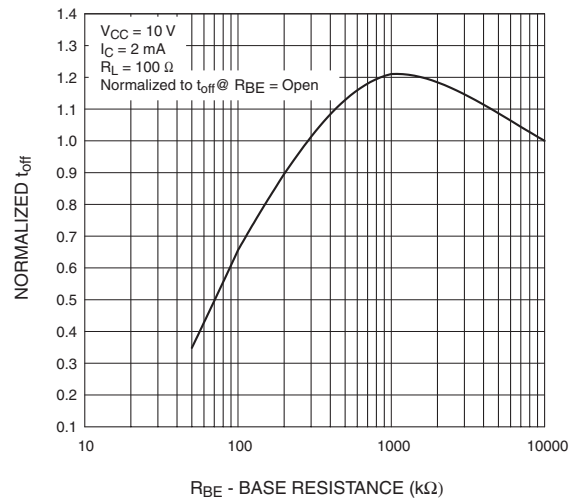


Fig. 8 Normalized t_{off} vs. R_{BE}



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Fig. 9 Switching Speed vs. Load Resistor

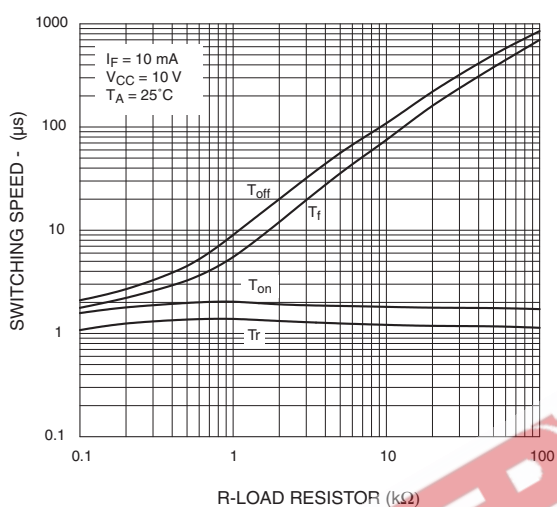
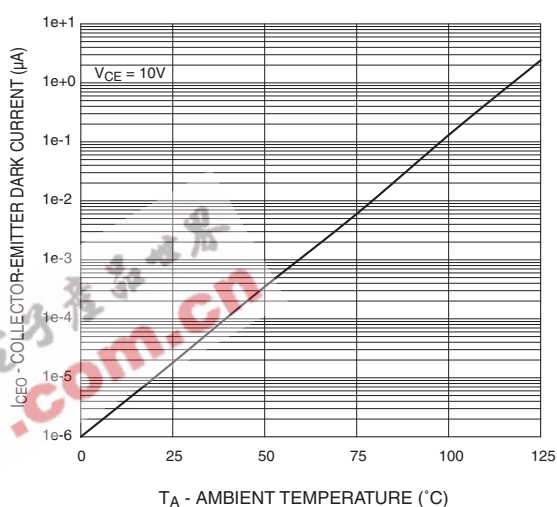
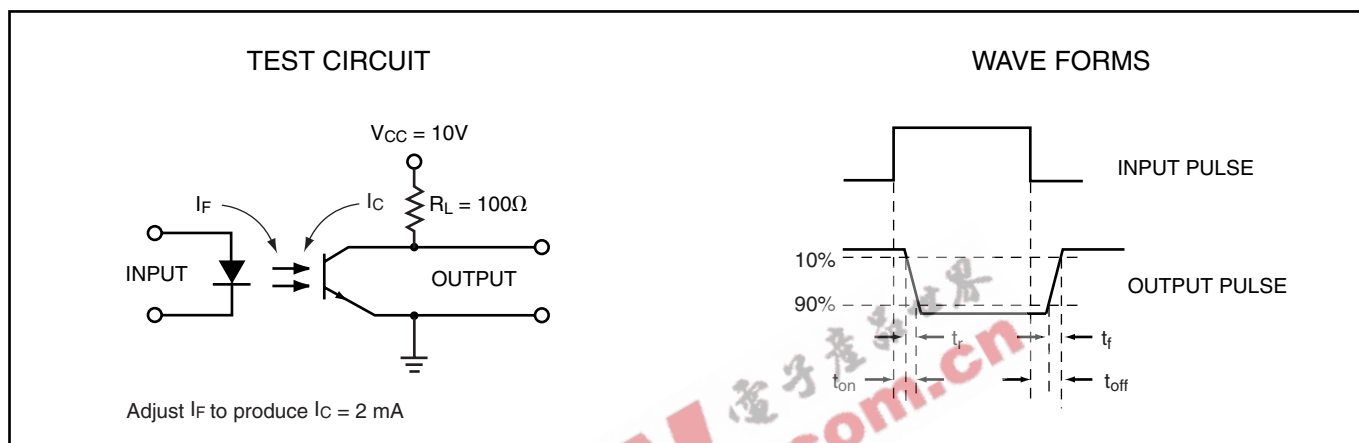


Fig. 10 Dark current vs. Ambient Temperature.



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Figure 7. Switching Time Test Circuit and Waveforms



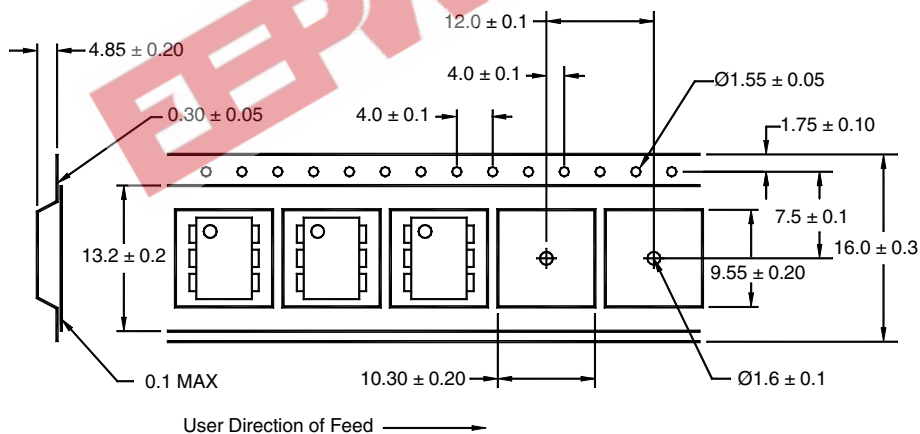
6-PIN DIP OPTOCOUPLEDERS FOR POWER SUPPLY APPLICATIONS (NO BASE CONNECTION)

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ORDERING INFORMATION

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4" Lead Spacing
300	.300	VDE 0884
300W	.300W	VDE 0884, 0.4" Lead Spacing
3S	.3S	VDE 0884, Surface Mount
3SD	.3SD	VDE 0884, Surface Mount, Tape & Reel

QT Carrier Tape Specifications ("D" Taping Orientation)



NOTE

All dimensions are in inches (millimeters)

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